# VS-VSKDS203/100

**Vishay Semiconductors** 



## ADD-A-PAK Gen 7 **Power Modules Schottky Rectifier, 100 A**



| PRODUCT SUMMARY    |                            |  |  |  |  |
|--------------------|----------------------------|--|--|--|--|
| I <sub>F(AV)</sub> | 100 A                      |  |  |  |  |
| V <sub>R</sub>     | 100 V                      |  |  |  |  |
| Package            | ADD-A-PAK Gen 7            |  |  |  |  |
| Circuit            | Two diodes doubler circuit |  |  |  |  |

## **MECHANICAL DESCRIPTION**

The ADD-A-PAK Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

## **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **BENEFITS**

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

## **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKDS203.. Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS |   |             |       |  |  |
|-----------------------------------|---|-------------|-------|--|--|
| SYMBOL                            | CHARACTERISTICS                               | VALUES      | UNITS |  |  |
| I <sub>F(AV)</sub>                | Rectangular waveform                          | 100         | А     |  |  |
| V <sub>RRM</sub>                  |   | 100         | V     |  |  |
| I <sub>FSM</sub>                  | t <sub>p</sub> = 5 μs sine                    | 12 800      | А     |  |  |
| V <sub>F</sub>                    | 100 A <sub>pk</sub> , T <sub>J</sub> = 125 °C | 0.87        | V     |  |  |
| TJ                                | Range   | -55 to +175 | °C    |  |  |

| VOLTAGE RATINGS                           |                  |                 |       |  |  |  |
|---|------------------|-----------------|-------|--|--|--|
| PARAMETER                                 | SYMBOL           | VS-VSKDS203/100 | UNITS |  |  |  |
| Maximum DC reverse voltage V <sub>R</sub> |                  | 100             | V     |  |  |  |
| Maximum working peak reverse voltage      | V <sub>RWM</sub> | 100             | v     |  |  |  |

RoHS COMPLIANT

# VS-VSKDS203/100

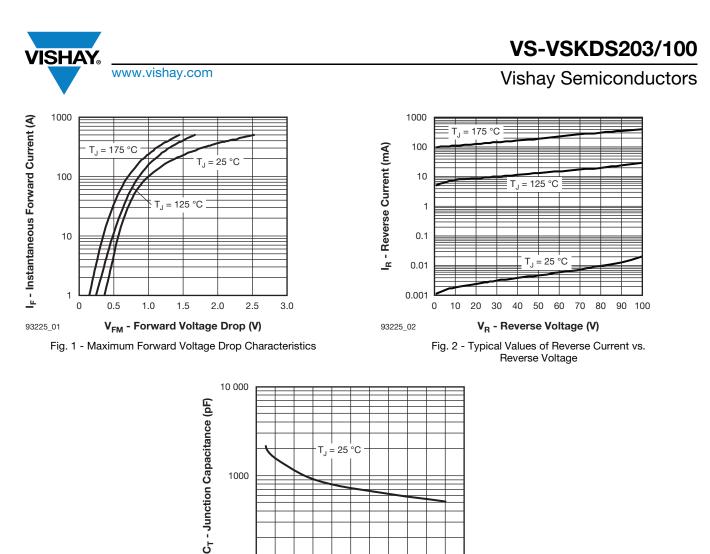


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| ABSOLUTE MAXIMUM RATINGS                |                                  |   |  |        |    |  |
|---|----------------------------------|---|--|--------|----|--|
| PARAMETER                               | PARAMETER SYMBOL TEST CONDITIONS |   | VALUES   | UNITS  |    |  |
| Maximum average forward current per leg | I <sub>F(AV)</sub>               | 50 % duty cycle at $T_C$ = 121 °C   | , rectangular waveform   | 100    |    |  |
| Maximum peak one cycle non-repetitive   | 1=0.1                            | 5 µs sine or 3 µs rect. pulse   | Following any rated<br>load condition and with<br>rated V <sub>RRM</sub> applied | 12 800 | А  |  |
| surge current                           | IFSM                             | 10 ms sine or 6 ms rect. pulse  |  | 1700   |    |  |
| Non-repetitive avalanche energy         | E <sub>AS</sub>                  | $T_J = 25 \text{ °C}, I_{AS} = 5.5 \text{ A}, L = 1 \text{ mH}$   |  | 15     | mJ |  |
| Repetitive avalanche current            | I <sub>AR</sub>                  | Current decaying linearly to zero in 1 $\mu$ s<br>Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical |  | А      |    |  |

| ELECTRICAL SPECIFICATIONS                   |                  |  |                                       |                            |       |  |
|---|------------------|--|---------------------------------------|----------------------------|-------|--|
| PARAMETER                                   | SYMBOL           | TEST CONDITIONS  |                                       | VALUES                     | UNITS |  |
| Maximum forward voltage drop                | V <sub>FM</sub>  | 100 A  | - T <sub>J</sub> = 25 °C              | 0.99                       | V     |  |
|   |                  | 200 A  |                                       | 1.34                       |       |  |
|   |                  | 100 A  | - T <sub>J</sub> = 125 °C             | 0.87                       |       |  |
|   |                  | 200 A  |                                       | 1.09                       |       |  |
| Maximum reverse leakage current             | I <sub>RM</sub>  | T <sub>J</sub> = 25 °C   | V <sub>R</sub> = Rated V <sub>R</sub> | 3                          | mA    |  |
| Maximum reverse leakage current             |                  | T <sub>J</sub> = 125 °C  |                                       | 65                         |       |  |
| Maximum junction capacitance C <sub>T</sub> |                  | $V_{\text{R}}$ = 5 $V_{\text{DC}}$ (test signal range 100 kHz to 1 MHz), 25 °C |                                       | 2750                       | pF    |  |
| Typical series inductance                   | L <sub>S</sub>   | Measured lead to lead 5 mm from package body                                   |                                       | 7.0                        | nH    |  |
| Maximum voltage rate of change              | dV/dt            | Rated V <sub>R</sub>   |                                       | 10 000                     | V/µs  |  |
| Maximum RMS insulation voltage              | V <sub>INS</sub> | 50 Hz  |                                       | 3000 (1 min)<br>3600 (1 s) | V     |  |

| THERMAL - MECHANICAL SPECIFICATIONS                     |             |                                   |  |             |          |
|---|-------------|-----------------------------------|--|-------------|----------|
| PARAMETER   |             | SYMBOL                            | TEST CONDITIONS  | VALUES      | UNITS    |
| Maximum junction and storage temperature range          | 9           | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to +175 | °C       |
| Maximum thermal resistance, junction to case per leg    |             | R <sub>thJC</sub>                 | DC operation   | 0.52        | °C/W     |
| Typical thermal resistance, case to heatsink per module |             | R <sub>thCS</sub>                 |  | 0.1         | 0/10     |
| Approximate weight                                      |             |                                   |  | 75          | g        |
|   |             |                                   |  | 2.7         | oz.      |
| Mounting torque ± 10 %                                  | to heatsink |                                   | A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the | 4           | Nm       |
|   | busbar      |                                   | spread of the compound.  | 3           |          |
| Case style  |             |                                   | JEDEC®   | TO-240AA co | mpatible |



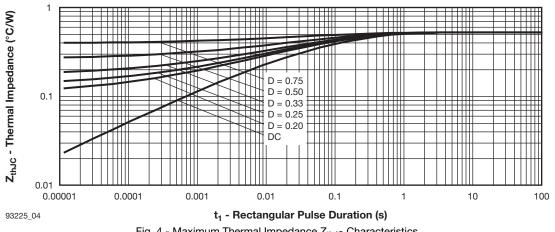
V<sub>R</sub> - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

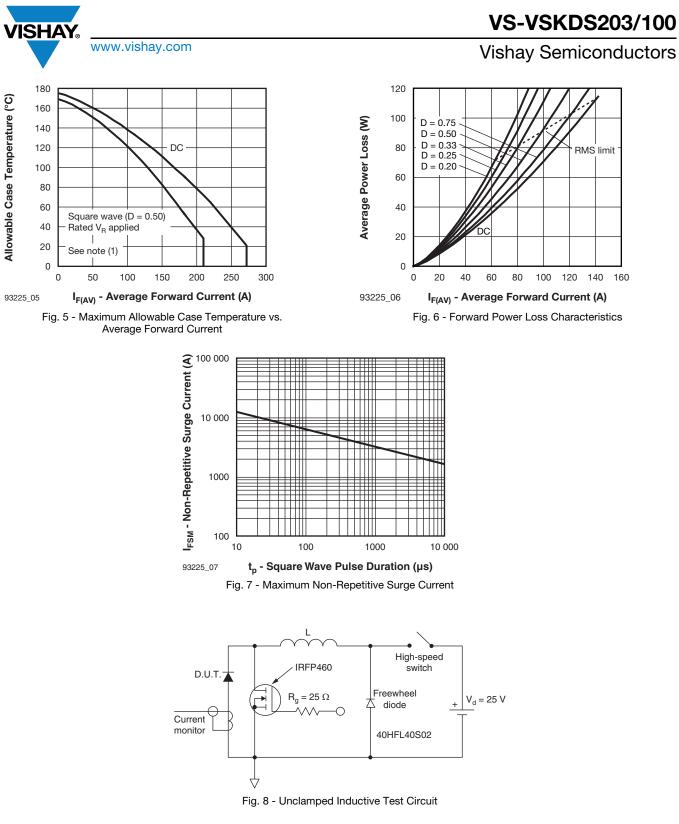
0 10 20 30 40 50 60 70 80 90 100 110

1000

100

93225\_03





#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$

Revision: 29-Sep-15

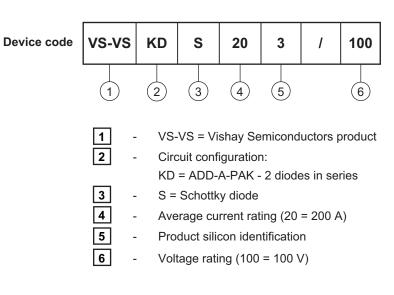
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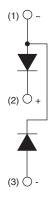
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### **ORDERING INFORMATION TABLE**



### **CIRCUIT CONFIGURATION**



| Dimensions www.vishav.com/doc?95369 | LINKS TO RELATED DOCUMENTS |                          |  |  |  |  |
|-------------------------------------|----------------------------|--------------------------|--|--|--|--|
|                                     | Dimensions                 | www.vishay.com/doc?95369 |  |  |  |  |

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## **ADD-A-PAK Generation VII - Diode**

## **DIMENSIONS** in millimeters (inches)





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